## Accelerating WBG Power Semiconductor Technology Commercialization

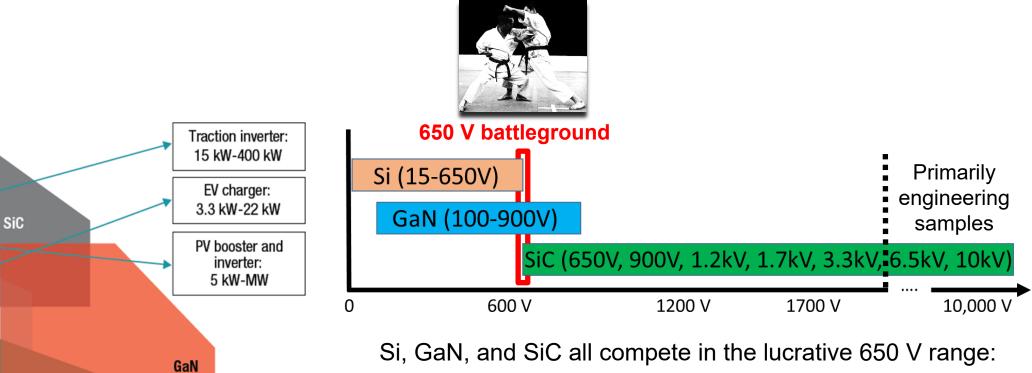


Victor Veliadis, Ph.D. Executive Director & CTO, PowerAmerica Professor in ECE, North Carolina State University



Si/SiC/GaN Power Device Selection is Driven by Voltage, Current, Power Density (Frequency), Efficiency, Temperature, and Cost





- *Si* is reliable, rugged, cheap, capable of high currents, and has device/circuit design legacy
- SiC is efficient and operates at high currents and frequency
- *GaN* offers efficient very high frequency operation at reasonable cost

Source: Texas Instruments

**IGBT/GTO** 

Si SJ

10 kHz

100 kHz

Frequency

1 MHz

10 MHz

1 MW

100 kW

10 kW

1 kW

100 W

10 W

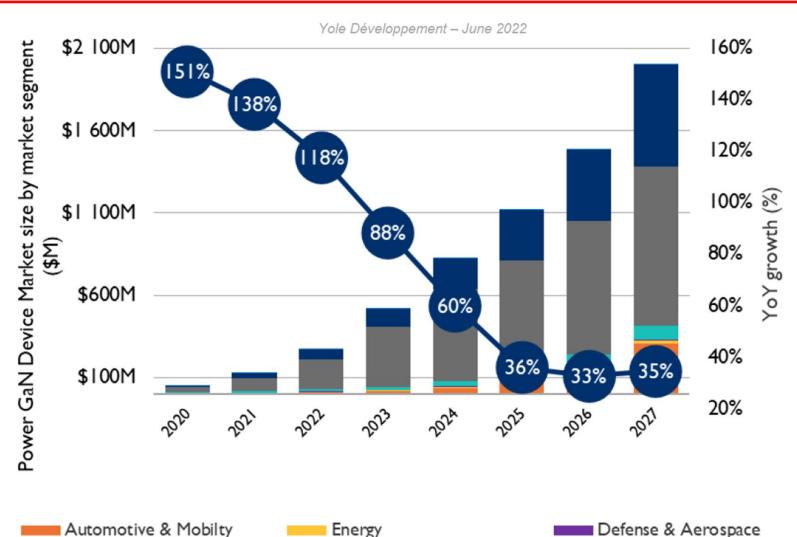
Si

1 kHz

Power

# The GaN Power Device Market is Dominated by Consumer Applications and is Projected to Reach \$2B by 2027

Telecom & Infrastructure



Mobile & Consumer

YoY growth (%)

The GaN market is dominated by consumer applications, with devices in mobile phones and laptop fast chargers.

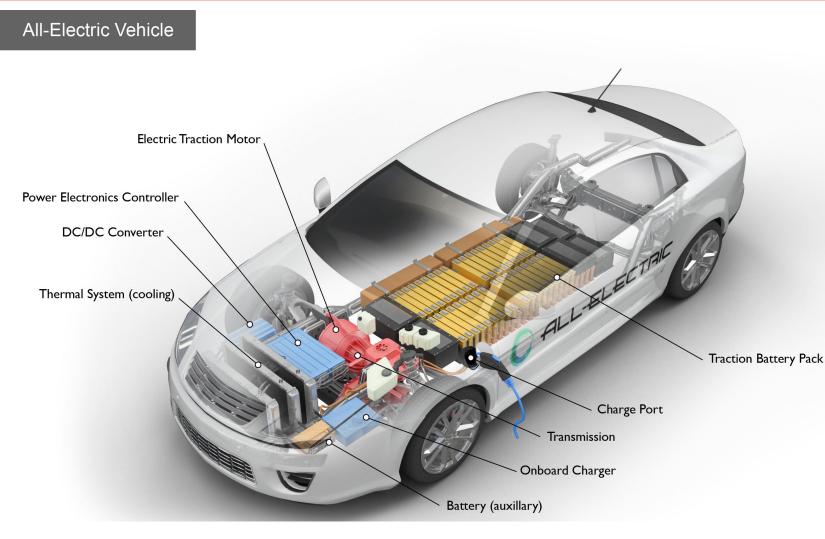


Industrial

Others



# Vehicle Electrification is the Mass Commercialization Opportunity for SiC Power Electronics (and GaN)



https://afdc.energy.gov/vehicles/how-do-all-electric-cars-work

4 211 Million SiC MOSFETs in TESLA EV traction inverters alone!

#### **EV** Power Electronics

**Traction inverter and motor**: Uses power from the traction battery pack to drive the vehicle's wheels

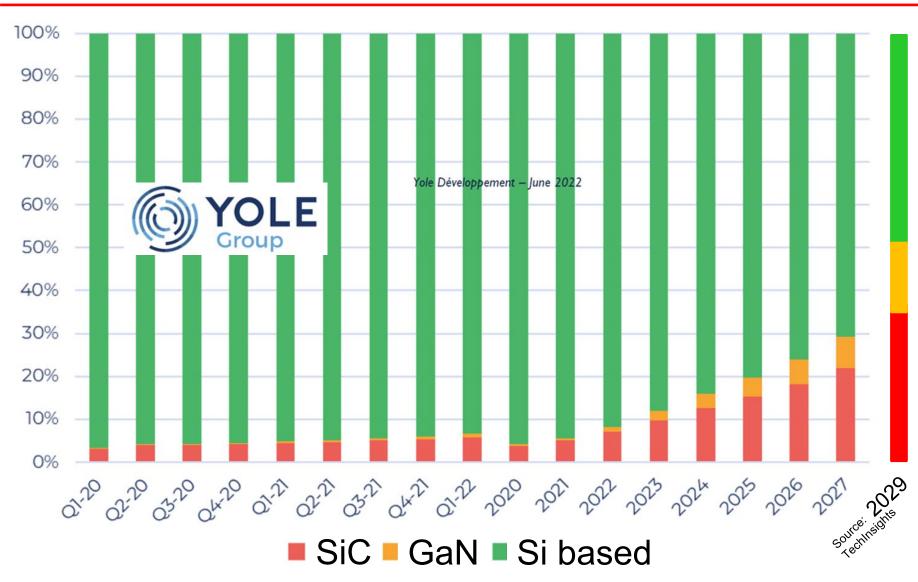
**DC/DC converter:** This device converts higher-voltage DC power from the traction battery pack to the lower-voltage DC power needed to run vehicle accessories and recharge the auxiliary battery.

**Onboard charger:** Takes the incoming AC electricity supplied via the charge port and converts it to DC power for charging the traction battery.

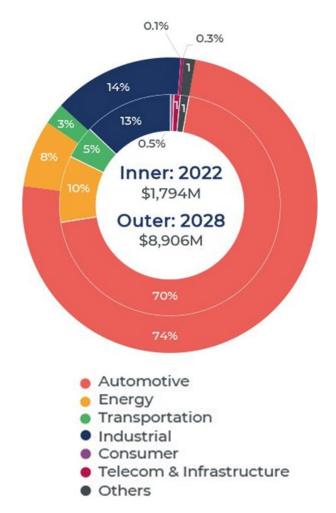
**PTC Heater Module:** The positive temperature coefficient (PTC) heater is a self-regulated heating device that uses electricity to supply efficient heat control for various vehicle systems, including invehicle air conditioning and battery thermal management.

The SiC Power Device Market is Projected to Reach US\$8.9B in 2028, with 70% of that Attributed to Automotive





Silicon devices include: Rectifiers, Thyristors, bipolar, X-FETs such as MOSFETs and JFETs, IGBTs, and modules/IPMs.



Mass Commercialization Brings Economies of Scale to WBG



Barriers to mass commercialization:

- High device cost
- · Defects and scalability of device area
- Reliability/Ruggedness concerns
- Need for workforce training











PowerAmerica is a memberdriven consortium of industry, universities, and national labs, accelerating the commercialization of energyefficient SiC and GaN power semiconductor chips and power electronics. Our membership spans the WBG technology ecosystem, including the leading universities that train the workforce. PowerAmerica catalyzes semiconductor manufacturing job creation and is a critical enabler of the "electrification of everything" which is vital in the push for decarbonization and energy sustainability.



PowerAmericaInstitute.org

### PowerAmerica's **\$156M** Investment in **212** Power SiC and GaN Projects Addressed All Major Technology Areas



**PowerAmerica's \$150M in power SiC and GaN projects address design, fabrication, testing, modules, reliability, ruggedness, and all major applications** including automotive and rail traction, on-board chargers, photovoltaic, consumer electronics, aerospace, flexible alternative current transmission systems (FACTS), high-voltage DC systems (HVDC), microgrids, energy storage, wind power, motor drives, UPS, and data centers.

Execution of these seed projects demonstrates SiC and GaN competitive system advantages. The outcomes are industry investment in these technologies that creates high-tech manufacturing jobs and energy savings (reductions in  $CO_2$  emissions); both crucial to U.S. economy and national security.

PowerAmerica <b>\$145M</b> investment	2016	2017	2018	2019	2020	Total
Industry Projects	14	14	16	15	14	73
Academic Projects	18	25	19	24	26	112
National Lab Projects	2	2	2	2	3	11
Yearly projects	34	41	37	41	43	196
Industry Projects 2016-2020						73
Academic Projects 2016-2020						112

The 196 Project Areas:

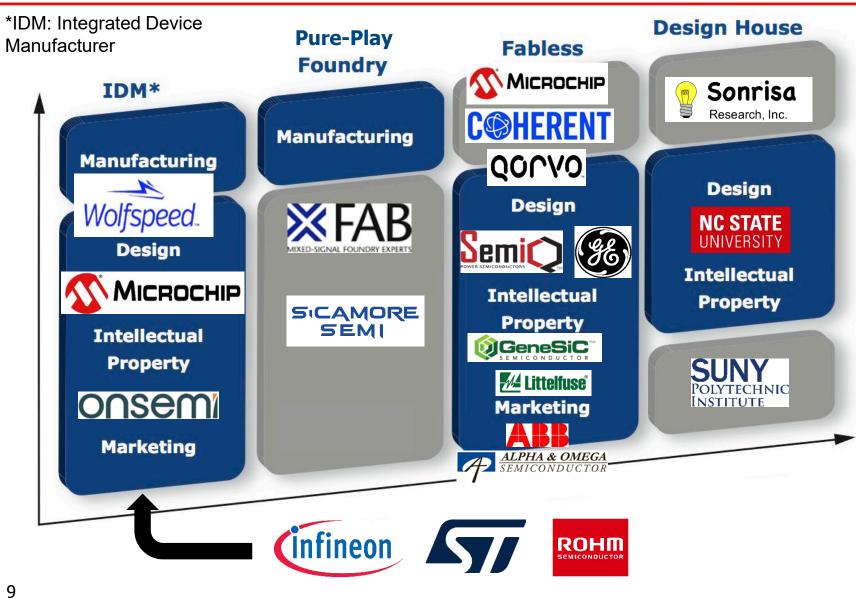
67 SiC Device and Fabrication

28 Modules and Reliability

- 24 Low-Voltage GaN Applications
- 40 Low-Voltage SiC Applications
- 21 Medium-Voltage SiC Applications
- 20 Education and Workforce training

16 additional projects since 2021

# The U.S. Mature SiC Fab Infrastructure Mirrors that of Si

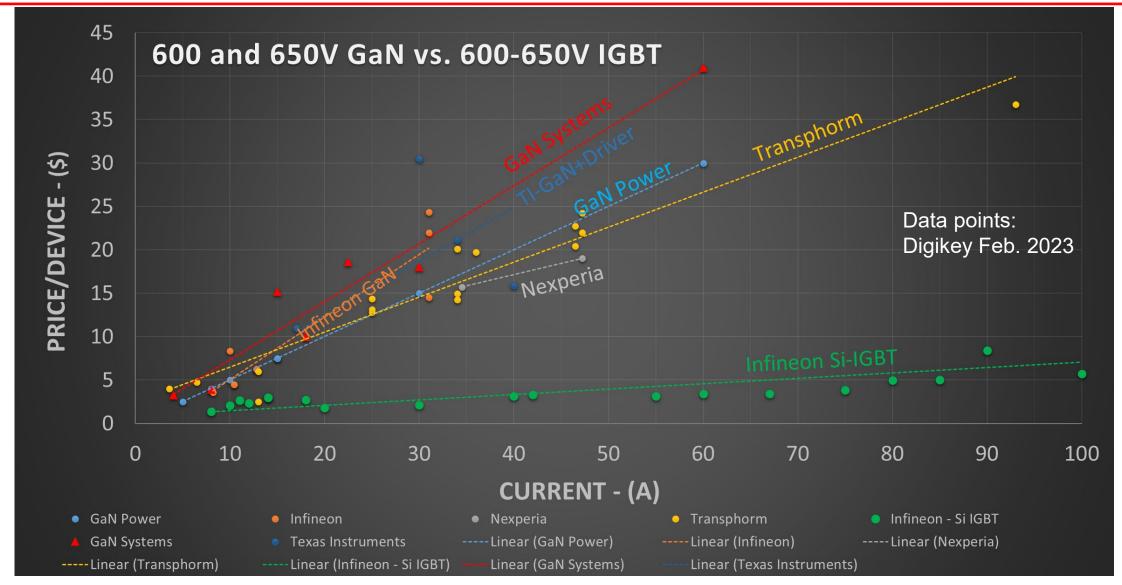




### SiC Fab particulars:

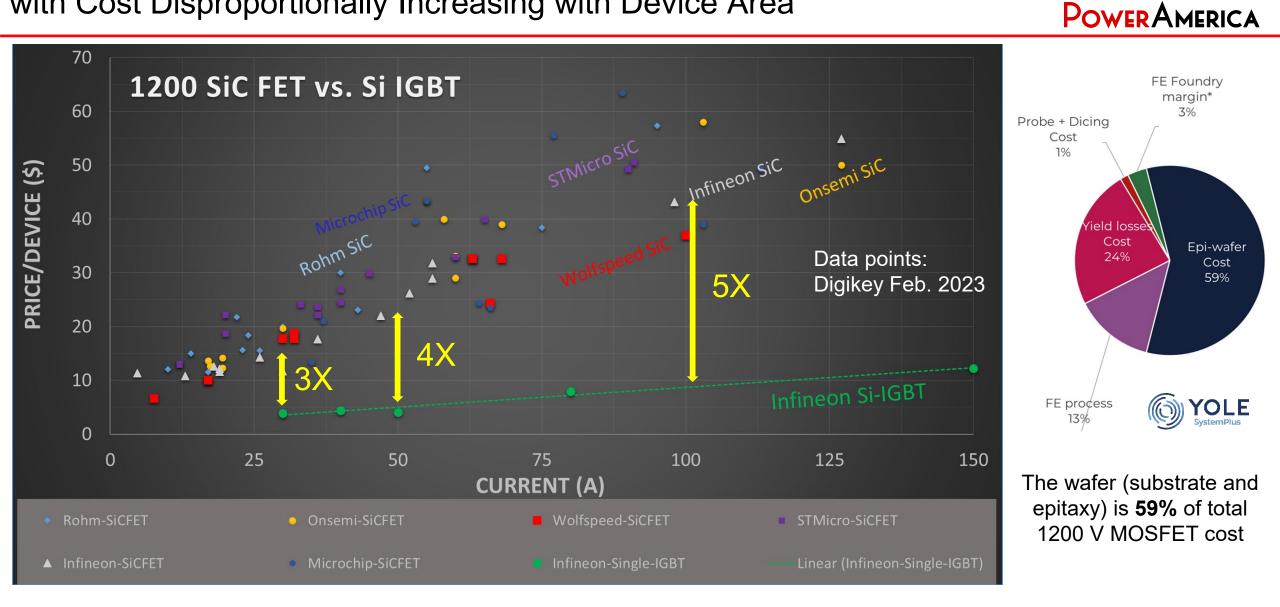
- Compete on process in addition to design
- Wafer quality and supply chain concerns

650 V GaN HEMTs Are More Expensive Than Similarly Rated Si Devices with Cost Disproportionally Increasing with Device Area



PowerAmerica

1200 V SiC MOSFETs Are More Expensive Than Similarly Rated Si Devices with Cost Disproportionally Increasing with Device Area



## SiC MOSFETs Enable System Mass and Volume **Reductions to Achieve Overall Cost Advantage**





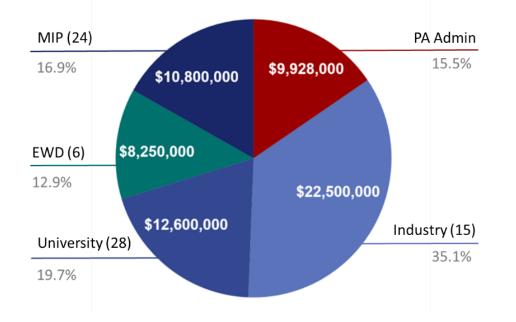
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Price parity can be achieved at the system level due to reduced mass/volume of magnetics, and simplified thermal management. For Mass Commercialization: cost savings at the system level <u>must</u> outweigh the higher cost of manufacturing SiC devices. V. Veliadis

Lower system losses provide energy savings throughout the life of the system



U.S. Department of Energy \$64M PowerAmerica Renewal Will Fund 67 Projects Across the WBG Supply Chain



## Proposed \$64M allocation:

- \$10M to Operating Expenses and Outreach
- \$23M to 52 University projects
- \$23M to 15 Industry projects
- \$8M to Education and Workforce Training

**Objective:** Accelerate innovation in SiC materials, chip design, fab equipment and processes, advanced modules, passive circuit components and thermal management, **and** key applications including grid modernization, data centers, motor drives, transportation electrification, renewables, and energy transmission and storage.

### **Proposed Budget Allocation**





#### Power Electronics & Energy Conversion Workshop July 30<sup>th</sup> & 31<sup>st</sup> 8:00AM MT - 4:00PM MT Location: Albuquerque, New Mexico

Venue: State Bar of New Mexico Hosted By: Sandia National Laboratories

# Thanks for your attention!

# Questions?



V. Veliadis